



DMT4014LDV

PowerDI3333-8

Product Summary

| BV _{DSS} | Rds(on) Max | I⊵ Max Tc = +25°C |
|-------------------|-------------------------------|----------------------|
| | 19mΩ @ V _{GS} = 10V | 26.5A |
| 40V | 29mΩ @ V _{GS} = 4.5V | 21.8A |

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Wireless Charging
- DC-DC Converters
- Power Management

Features and Benefits

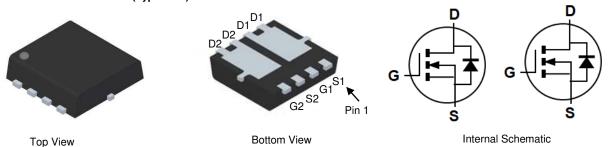
 100% Unclamped Inductive Switching (UIS) Test in Production — Ensures More Reliable and Robust End Application

40V N-CHANNEL ENHANCEMENT MODE MOSFET

- Low R_{DS(ON)} Ensures On-State Losses Are Minimized
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)



Ordering Information (Note 4)

| Part Number | Case | Packaging |
|---------------|--------------------------|-------------------|
| DMT4014LDV-7 | PowerDI3333-8 (Type UXC) | 2,000/Tape & Reel |
| DMT4014LDV-13 | PowerDI3333-8 (Type UXC) | 3,000/Tape & Reel |

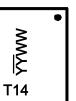
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



PowerDI3333-8 (Type UXC)

PowerDI3333-8 (Type UXC)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | |
|--|--------------|--|------|--------------|----|
| Drain-Source Voltage | | V _{DSS} | 40 | V | |
| Gate-Source Voltage | | Vgss | ±20 | V | |
| Continuous Drain Current (Note 6) $V_{GS} = 10V$ $T_C = +25^{\circ}$ $T_C = +70^{\circ}$ | | | lo | 26.5 21.2 | А |
| Continuous Drain Current (Note 6) V _{GS} = 10V | Steady State | T _A = +25°C T _A = +70°C | lo | 8.5 6.8 | А |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | | ldм | 100 | А | |
| Maximum Continuous Body Diode Forward Current (N | ls | 2.7 | А | | |
| Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%) | | | lsм | 100 | А |
| Avalanche Current, L = 0.1mH | | | las | 19.8 | А |
| Avalanche Energy, L = 0.1mH | | | Eas | 19.6 | mJ |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit |
|--|--------------|------------------|-------------|------|
| Total Power Dissipation (Note 5) | TA = +25°C | PD | 1.0 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | Reja | 124 | °C/W |
| Total Power Dissipation (Note 6) | TA = +25°C | PD | 2.1 | W |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State | R _{0JA} | 61 | °C/W |
| Thermal Resistance, Junction to Case (Note 6) | Rejc | 6.2 | °C/W | |
| Operating and Storage Temperature Range | | TJ, TSTG | -55 to +150 | °C |

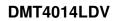
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

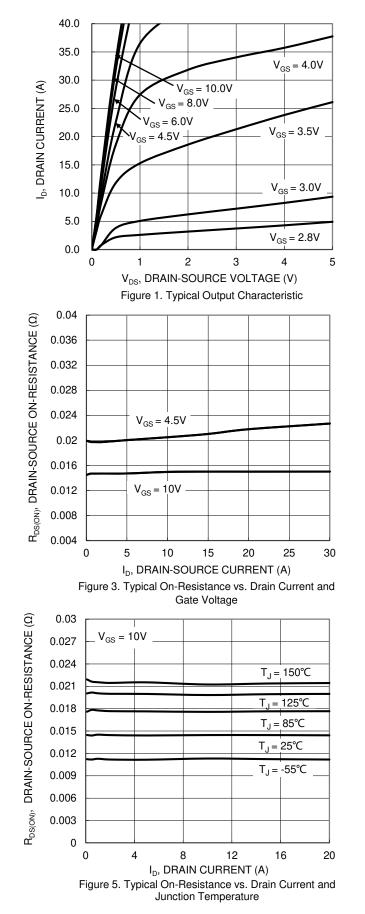
| | | | - | | | T 10 I''' | |
|--|-----------------|-----|------|------|------|---|--|
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
| OFF CHARACTERISTICS (Note 7) | | | | | | | |
| Drain-Source Breakdown Voltage | BVDSS | 40 | — | — | V | $V_{GS} = 0V, I_D = 1mA$ | |
| Zero Gate Voltage Drain Current | IDSS | — | — | 1 | μΑ | $V_{DS} = 32V, V_{GS} = 0V$ | |
| Gate-Source Leakage | lgss | — | — | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | VGS(TH) | 1 | — | 3 | V | $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | Description | — | 14.7 | 19 | | $V_{GS} = 10V, I_D = 20A$ | |
| Static Drain-Source On-Resistance | RDS(ON) | | 21.2 | 29 | mΩ | VGS = 4.5V, ID = 15A | |
| Diode Forward Voltage | Vsd | _ | 1.0 | 1.2 | V | V _{GS} = 0V, I _S = 20A | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | Ciss | | 750 | | pF | | |
| Output Capacitance | Coss | — | 225 | — | pF | VDS = 20V, VGS = 0V, f = 1MHz | |
| Reverse Transfer Capacitance | Crss | _ | 21 | _ | pF | | |
| Gate Resistance | Rg | _ | 1.1 | _ | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | — | 5.7 | _ | nC | | |
| Total Gate Charge (V _{GS} = 10V) | Qg | — | 11.2 | — | nC | | |
| Gate-Source Charge | Q _{gs} | — | 2.0 | _ | nC | $V_{DS} = 20V, I_{D} = 20A$ | |
| Gate-Drain Charge | Q _{gd} | — | 2.2 | — | nC | | |
| Turn-On Delay Time | td(on) | _ | 3.5 | _ | ns | | |
| Turn-On Rise Time | t _R | | 4.6 | _ | ns | $V_{GS} = 10V, V_{DD} = 20V,$ $R_g = 1.6\Omega, I_D = 20A$ | |
| Turn-Off Delay Time | tD(OFF) | _ | 12.4 | _ | ns | | |
| Turn-Off Fall Time | tF | _ | 4.9 | | ns | | |
| Body Diode Reverse Recovery Time | trr | _ | 11.3 | — | ns | IF = 15A, di/dt = 400A/μs | |
| Body Diode Reverse Recovery Charge | Q _{RR} | _ | 9.5 | _ | nC | | |

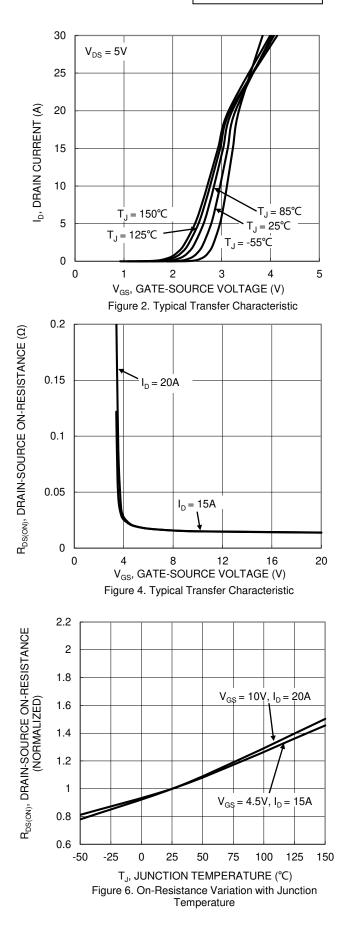
Notes:

5. Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided.
6. Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.



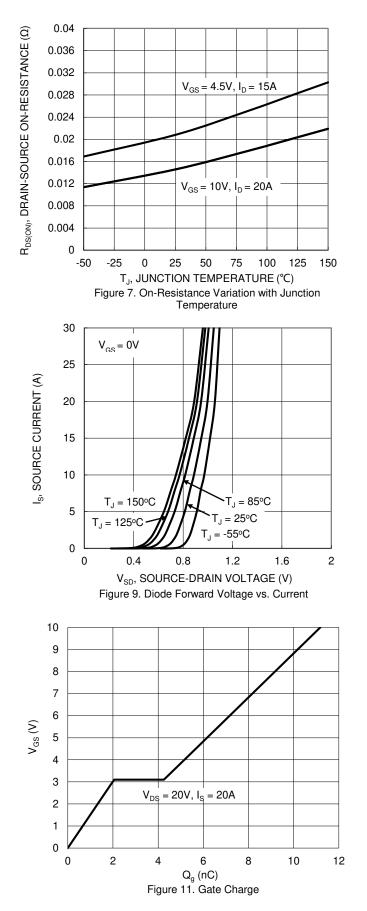


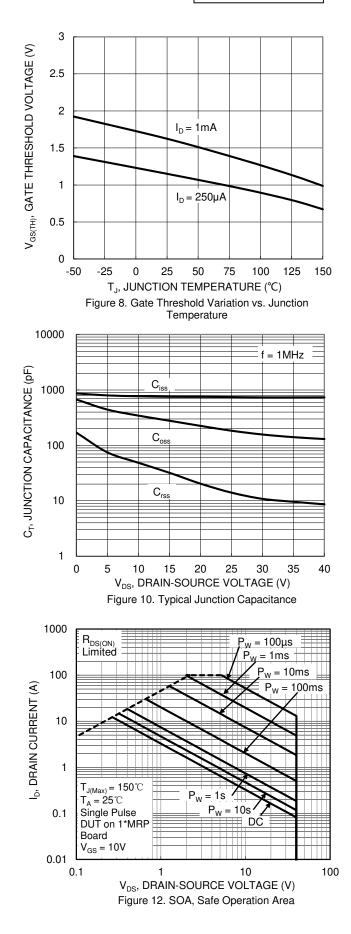






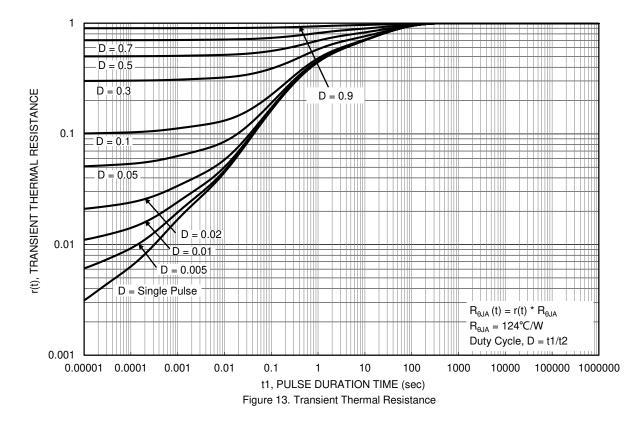
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DMT4014LDV Document number: DS42919 Rev. 2 - 2

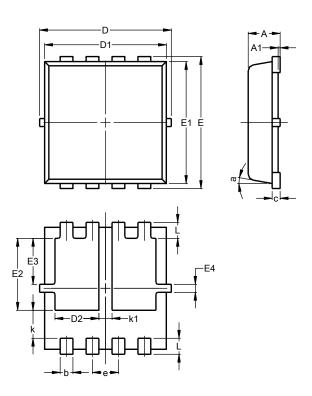






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

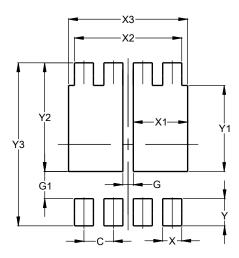


| | PowerDI3333-8 (Type UXC) | | | | |
|-------|-----------------------------|------|------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.75 | 0.85 | 0.80 | | |
| A1 | 0.00 | 0.05 | | | |
| b | 0.25 | 0.40 | 0.32 | | |
| С | 0.10 | 0.25 | 0.15 | | |
| D | 3.20 | 3.40 | 3.30 | | |
| D1 | 2.95 | 3.15 | 3.05 | | |
| D2 | 0.90 | 1.30 | 1.10 | | |
| E | 3.20 | 3.40 | 3.30 | | |
| E1 | 2.95 | 3.15 | 3.05 | | |
| E2 | 1.60 | 2.00 | 1.80 | | |
| E3 | 0.95 | 1.35 | 1.15 | | |
| E4 | 0.10 | 0.30 | 0.20 | | |
| е | _ | _ | 0.65 | | |
| L | 0.30 | 0.50 | 0.40 | | |
| k | 0.50 | 0.90 | 0.70 | | |
| k1 | 0.13 | 0.53 | 0.33 | | |
| а | 0° | 12° | 10° | | |
| All I | All Dimensions in mm | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UXC)



| Dimensions | Value (in mm) | | | |
|------------|---------------|--|--|--|
| С | 0.650 | | | |
| G | 0.230 | | | |
| G1 | 0.600 | | | |
| Х | 0.420 | | | |
| X1 | 1.200 | | | |
| X2 | 2.370 | | | |
| X3 | 2.630 | | | |
| Y | 0.600 | | | |
| Y1 | 1.900 | | | |
| Y2 | 2.400 | | | |
| Y3 | 3.600 | | | |



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